

300V NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

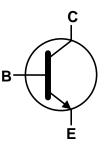
- BV_{CEO} > 300V
- Ideal for Medium Power Amplification and Switching
- Complementary PNP Type: MMBTA92
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

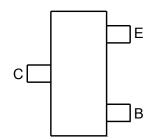
- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish-Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

Ordering Information (Notes 4 & 5)

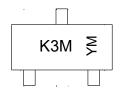
Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBTA42-7-F	AEC-Q101	K3M	7	8	3,000
MMBTA42-13-F	AEC-Q101	K3M	13	8	10,000
MMBTA42Q-7-F	Automotive	K3M	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SOT23



K3M = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026
Code	С	D	Е	F	G	Н		J	K	L	М	N
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	300	V	
Collector-Emitter Voltage	V _{CEO}	300	V	
Emitter-Base Voltage	V _{EBO}	6.0	V	
Collector Current - Continuous	Ic	500	mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient (Note 6)		$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

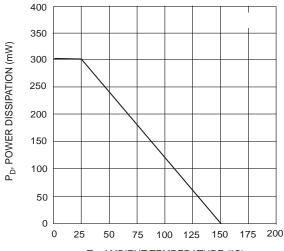
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	BV _{CBO}	300	_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	300	_	V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0		V	$I_E = 100 \mu A, I_C = 0$
Collector Cut-Off Current	I _{CBO}		100	nA	$V_{CB} = 200V, I_{E} = 0$
Emitter Cut-Off Current	I _{EBO}		100	nA	$V_{EB} = 6.0V, I_C = 0$
ON CHARACTERISTICS (Note 8)					
		25	_		$I_C = 1.0 \text{mA}, V_{CE} = 10 \text{V}$
DC Current Gain	h _{FE}	40	_	_	$I_C = 10mA, V_{CE} = 10V$
		40			$I_C = 30mA, V_{CE} = 10V$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		0.5	V	$I_C = 20 \text{mA}, I_B = 2.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}		0.9	V	$I_C = 20mA$, $I_B = 2.0mA$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{cb}		3.0	pF	$V_{CB} = 20V$, $f = 1.0MHz$, $I_E = 0$
Current Gain-Bandwidth Product	f⊤	50	_	MHz	$V_{CE} = 20V$, $I_C = 10mA$, $f = 100MHz$

Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics



T_A, AMBIENT TEMPERATURE (°C) Fig. 1, Max Power Dissipation vs Ambient Temperature

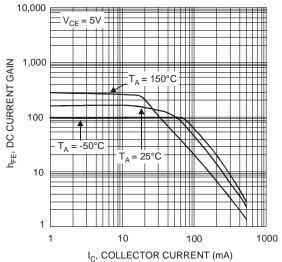
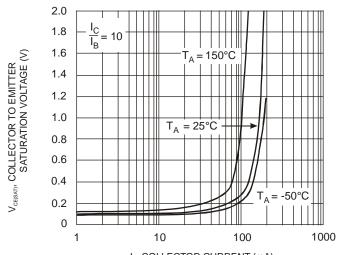
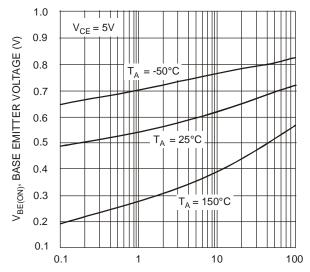


Fig. 3, DC Current Gain vs Collector Current

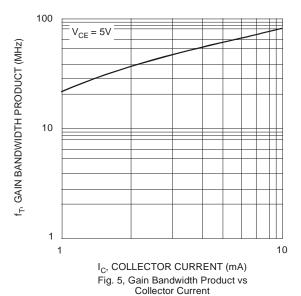


I_c, COLLECTOR CURRENT (mA) Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current



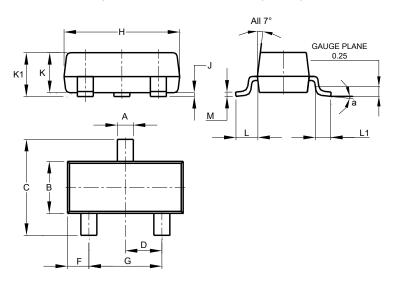
 $\rm I_c$, COLLECTOR CURRENT (mA) Fig. 4, Base Emitter Voltage vs Collector Current





Package Outline Dimensions

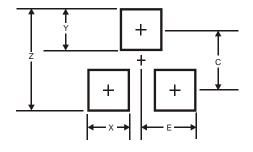
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
7	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	8°					
All	All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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